

# NX3L1G66

## Low-voltage analog switch

Rev. 02 — 7 March 2008

Product data sheet

## 1. General description

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The NX3L1G66 provides one single pole, single-throw analog switch function. It has two input/output terminals (Y and Z) and an active HIGH enable input pin (E). When E is LOW, the analog switch is turned off.

Schmitt trigger action at the enable input (E) makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 1.4 V to 3.6 V.

The NX3L1G66 allows signals with amplitude up to  $V_{CC}$  to be transmitted from Y to Z; or from Z to Y. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

## 2. Features

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- Wide supply voltage range from 1.4 V to 3.6 V
- Very low ON resistance (peak):
  - ◆ 1.6  $\Omega$  (typical) at  $V_{CC} = 1.4$  V
  - ◆ 1.0  $\Omega$  (typical) at  $V_{CC} = 1.65$  V
  - ◆ 0.55  $\Omega$  (typical) at  $V_{CC} = 2.3$  V
  - ◆ 0.50  $\Omega$  (typical) at  $V_{CC} = 2.7$  V
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114E Class 3A exceeds 7500 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from  $-40$  °C to  $+85$  °C and from  $-40$  °C to  $+125$  °C

## 3. Applications

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- Cell phone
- PDA
- Portable media player

## 4. Ordering information

Table 1. Ordering information

| Type number | Package           |       |   | Version |
|-------------|-------------------|-------|---|---------|
|             | Temperature range | Name  | Description   |         |
| NX3L1G66GM  | -40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm | SOT886  |

## 5. Marking

Table 2. Marking codes

| Type number | Marking code |
|-------------|--------------|
| NX3L1G66GM  | DL           |

## 6. Functional diagram

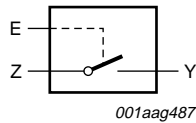


Fig 1. Logic symbol

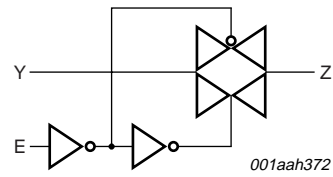


Fig 2. Logic diagram

## 7. Pinning information

### 7.1 Pinning

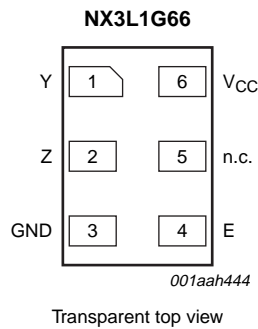


Fig 3. Pin configuration SOT886 (XSON6)

## 7.2 Pin description

**Table 3.** Pin description

| Symbol          | Pin | Description                 |
|-----------------|-----|-----------------------------|
| Y               | 1   | independent input or output |
| Z               | 2   | independent input or output |
| GND             | 3   | ground (0 V)                |
| E               | 4   | enable input (active HIGH)  |
| n.c.            | 5   | not connected               |
| V <sub>CC</sub> | 6   | supply voltage              |

## 8. Functional description

**Table 4.** Function table<sup>[1]</sup>

| Input E | Switch    |
|---------|-----------|
| L       | OFF-state |
| H       | ON-state  |

- [1] H = HIGH voltage level;  
L = LOW voltage level.

## 9. Limiting values

**Table 5.** Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions  | Min                 | Max                   | Unit |
|------------------|-------------------------|---|---------------------|-----------------------|------|
| V <sub>CC</sub>  | supply voltage          |   | -0.5                | +4.6                  | V    |
| V <sub>I</sub>   | input voltage           |   | <sup>[1]</sup> -0.5 | +4.6                  | V    |
| V <sub>SW</sub>  | switch voltage          |   | <sup>[2]</sup> -0.5 | V <sub>CC</sub> + 0.5 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < -0.5 V   | -50                 | -                     | mA   |
| I <sub>SK</sub>  | switch clamping current | V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V   | -                   | ±50                   | mA   |
| I <sub>SW</sub>  | switch current          | V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V;<br>source or sink current                                      | -                   | ±350                  | mA   |
|                  |                         | V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V;<br>pulsed at 1 ms duration, < 10 % duty cycle;<br>peak current | -                   | ±500                  | mA   |
| T <sub>stg</sub> | storage temperature     |   | -65                 | +150                  | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C  | <sup>[3]</sup> -    | 250                   | mW   |

- [1] The minimum input voltage rating may be exceeded if the input current rating is observed.  
 [2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.  
 [3] For XSON6 packages: above 45 °C the value of P<sub>tot</sub> derates linearly with 2.4 mW/K.

## 10. Recommended operating conditions

**Table 6. Recommended operating conditions**

| Symbol              | Parameter                           | Conditions                              | Min   | Max      | Unit |
|---------------------|-------------------------------------|---|-------|----------|------|
| $V_{CC}$            | supply voltage                      |   | 1.4   | 3.6      | V    |
| $V_I$               | input voltage                       | enable input E                          | 0     | 3.6      | V    |
| $V_{SW}$            | switch voltage                      |   | [1] 0 | $V_{CC}$ | V    |
| $T_{amb}$           | ambient temperature                 |   | -40   | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.4\text{ V to }3.6\text{ V}$ | [2] - | 200      | ns/V |

[1] To avoid sinking GND current from of terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Y. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

## 11. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol       | Parameter                 | Conditions  | 25 °C        |     |              | -40 °C to +125 °C |              |              | Unit          |
|--------------|---------------------------|---|--------------|-----|--------------|-------------------|--------------|--------------|---------------|
|              |                           |   | Min          | Typ | Max          | Min               | Max (85 °C)  | Max (125 °C) |               |
| $V_{IH}$     | HIGH-level input voltage  | $V_{CC} = 1.4\text{ V to }1.95\text{ V}$  | $0.65V_{CC}$ | -   | -            | $0.65V_{CC}$      | -            | -            | V             |
|              |                           | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$   | 1.7          | -   | -            | 1.7               | -            | -            | V             |
|              |                           | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$   | 2.0          | -   | -            | 2.0               | -            | -            | V             |
| $V_{IL}$     | LOW-level input voltage   | $V_{CC} = 1.4\text{ V to }1.95\text{ V}$  | -            | -   | $0.35V_{CC}$ | -                 | $0.35V_{CC}$ | $0.35V_{CC}$ | V             |
|              |                           | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$   | -            | -   | 0.7          | -                 | 0.7          | 0.7          | V             |
|              |                           | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$   | -            | -   | 0.8          | -                 | 0.8          | 0.8          | V             |
| $I_I$        | input leakage current     | enable input E;<br>$V_I = \text{GND to }3.6\text{ V};$<br>$V_{CC} = 1.4\text{ V to }3.6\text{ V}$ | -            | -   | -            | -                 | $\pm 0.5$    | $\pm 1$      | $\mu\text{A}$ |
| $I_{S(OFF)}$ | OFF-state leakage current | Y port;<br>$V_{CC} = 1.4\text{ V to }3.6\text{ V};$<br>see <a href="#">Figure 4</a>               | -            | -   | $\pm 5$      | -                 | $\pm 50$     | $\pm 500$    | nA            |
| $I_{S(ON)}$  | ON-state leakage current  | Z port;<br>$V_{CC} = 1.4\text{ V to }3.6\text{ V};$<br>see <a href="#">Figure 5</a>               | -            | -   | $\pm 5$      | -                 | $\pm 50$     | $\pm 500$    | nA            |
| $I_{CC}$     | supply current            | $V_I = V_{CC}\text{ or GND};$<br>$V_{CC} = 3.6\text{ V};$<br>$V_{SW} = \text{GND or }V_{CC}$      | -            | -   | 100          | -                 | 690          | 6000         | nA            |
| $C_I$        | input capacitance         |   | -            | 1.0 | -            | -                 | -            | -            | pF            |
| $C_{S(OFF)}$ | OFF-state capacitance     |   | -            | 35  | -            | -                 | -            | -            | pF            |
| $C_{S(ON)}$  | ON-state capacitance      |   | -            | 110 | -            | -                 | -            | -            | pF            |

11.1 Test circuits

$V_I = 0.3\text{ V or } V_{CC} - 0.3\text{ V}; V_O = V_{CC} - 0.3\text{ V or } 0.3\text{ V}.$

**Fig 4. Test circuit for measuring OFF-state leakage current**

$V_I = 0.3\text{ V or } V_{CC} - 0.3\text{ V}; V_O = \text{open circuit}.$

**Fig 5. Test circuit for measuring ON-state leakage current**

11.2 ON resistance

Table 8. ON resistance

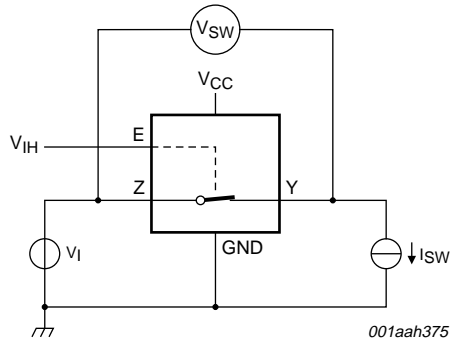
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see [Figure 7](#) to [Figure 12](#).

| Symbol                | Parameter                | Conditions   | -40 °C to +85 °C         |                    | -40 °C to +125 °C |     | Unit |      |   |
|-----------------------|--------------------------|--|--------------------------|--------------------|-------------------|-----|------|------|---|
|                       |                          |  | Min                      | Typ <sup>[1]</sup> | Max               | Min |      | Max  |   |
| R <sub>ON(peak)</sub> | ON resistance (peak)     | V <sub>I</sub> = GND to V <sub>CC</sub> ;<br>I <sub>SW</sub> = 100 mA;<br>see <a href="#">Figure 6</a> |                          |                    |                   |     |      |      |   |
|                       |                          |  | V <sub>CC</sub> = 1.4 V  | -                  | 1.6               | 3.7 | -    | 4.1  | Ω |
|                       |                          |  | V <sub>CC</sub> = 1.65 V | -                  | 1.0               | 1.6 | -    | 1.7  | Ω |
|                       |                          |  | V <sub>CC</sub> = 2.3 V  | -                  | 0.55              | 0.8 | -    | 0.9  | Ω |
|                       |                          | V <sub>CC</sub> = 2.7 V  | -                        | 0.5                | 0.75              | -   | 0.9  | Ω    |   |
| R <sub>ON(flat)</sub> | ON resistance (flatness) | V <sub>I</sub> = GND to V <sub>CC</sub> ;<br>I <sub>SW</sub> = 100 mA                                  |                          |                    |                   |     |      |      |   |
|                       |                          |  | V <sub>CC</sub> = 1.4 V  | -                  | 1.0               | 3.3 | -    | 3.6  | Ω |
|                       |                          |  | V <sub>CC</sub> = 1.65 V | -                  | 0.5               | 1.2 | -    | 1.3  | Ω |
|                       |                          |  | V <sub>CC</sub> = 2.3 V  | -                  | 0.15              | 0.3 | -    | 0.35 | Ω |
|                       |                          | V <sub>CC</sub> = 2.7 V  | -                        | 0.13               | 0.3               | -   | 0.35 | Ω    |   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C.

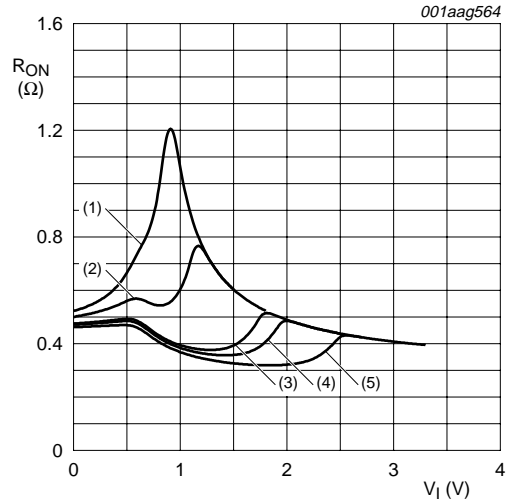
[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

11.3 ON resistance test circuit and graphs



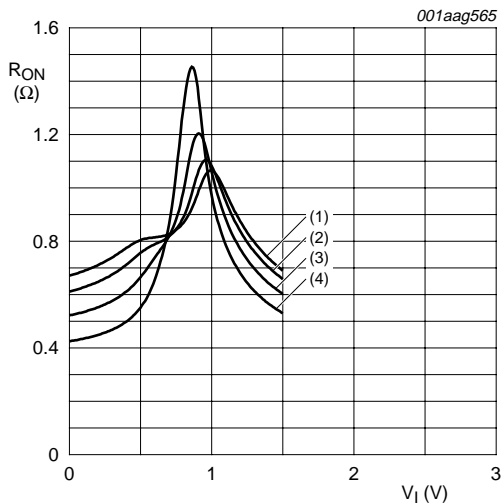
$R_{ON} = V_{SW} / I_{SW}$

Fig 6. Test circuit for measuring ON resistance



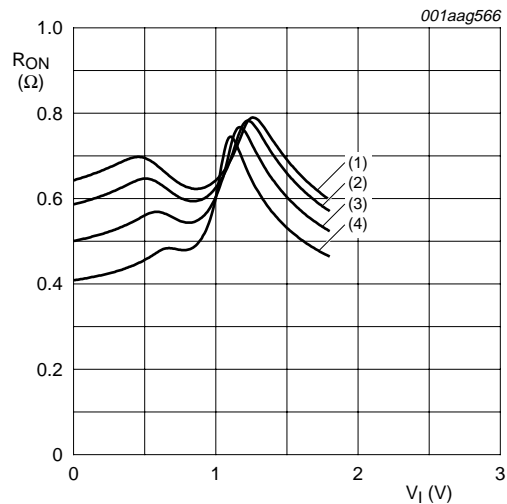
- (1)  $V_{CC} = 1.5\text{ V}$ .
  - (2)  $V_{CC} = 1.8\text{ V}$ .
  - (3)  $V_{CC} = 2.5\text{ V}$ .
  - (4)  $V_{CC} = 2.7\text{ V}$ .
  - (5)  $V_{CC} = 3.3\text{ V}$ .
- Measured at  $T_{amb} = 25\text{ }^\circ\text{C}$ .

Fig 7. Typical ON resistance as a function of input voltage



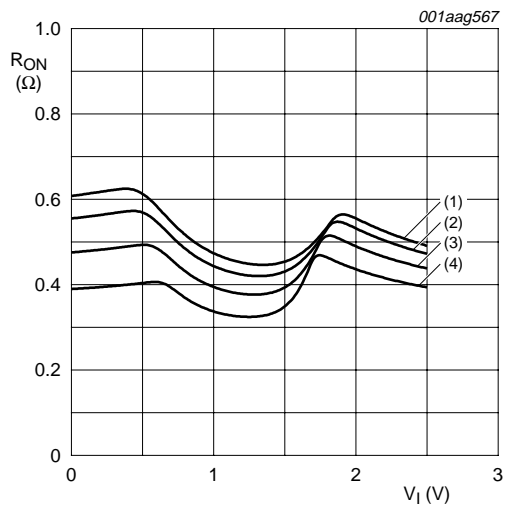
- (1)  $T_{amb} = 125\text{ }^\circ\text{C}$ .
- (2)  $T_{amb} = 85\text{ }^\circ\text{C}$ .
- (3)  $T_{amb} = 25\text{ }^\circ\text{C}$ .
- (4)  $T_{amb} = -40\text{ }^\circ\text{C}$ .

Fig 8. ON resistance as a function of input voltage;  $V_{CC} = 1.5\text{ V}$



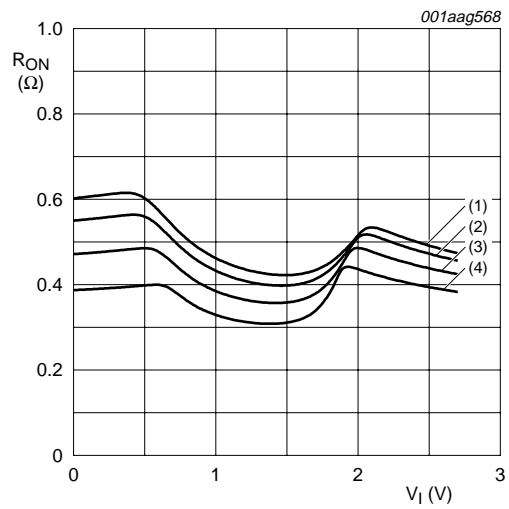
- (1)  $T_{amb} = 125\text{ }^\circ\text{C}$ .
- (2)  $T_{amb} = 85\text{ }^\circ\text{C}$ .
- (3)  $T_{amb} = 25\text{ }^\circ\text{C}$ .
- (4)  $T_{amb} = -40\text{ }^\circ\text{C}$ .

Fig 9. ON resistance as a function of input voltage;  $V_{CC} = 1.8\text{ V}$



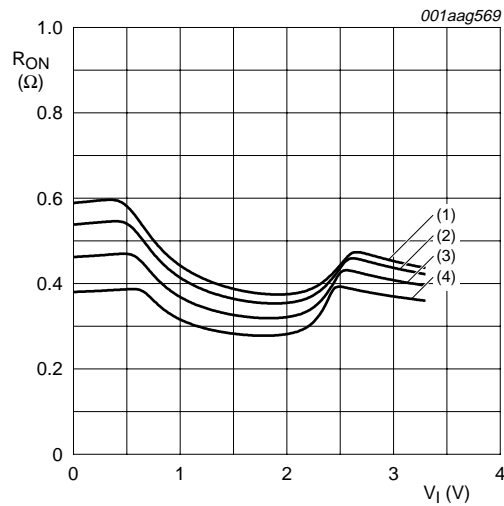
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

**Fig 10. ON resistance as a function of input voltage;  $V_{CC} = 2.5\text{ V}$**



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

**Fig 11. ON resistance as a function of input voltage;  $V_{CC} = 2.7\text{ V}$**



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

**Fig 12. ON resistance as a function of input voltage;  $V_{CC} = 3.3\text{ V}$**

## 12. Dynamic characteristics

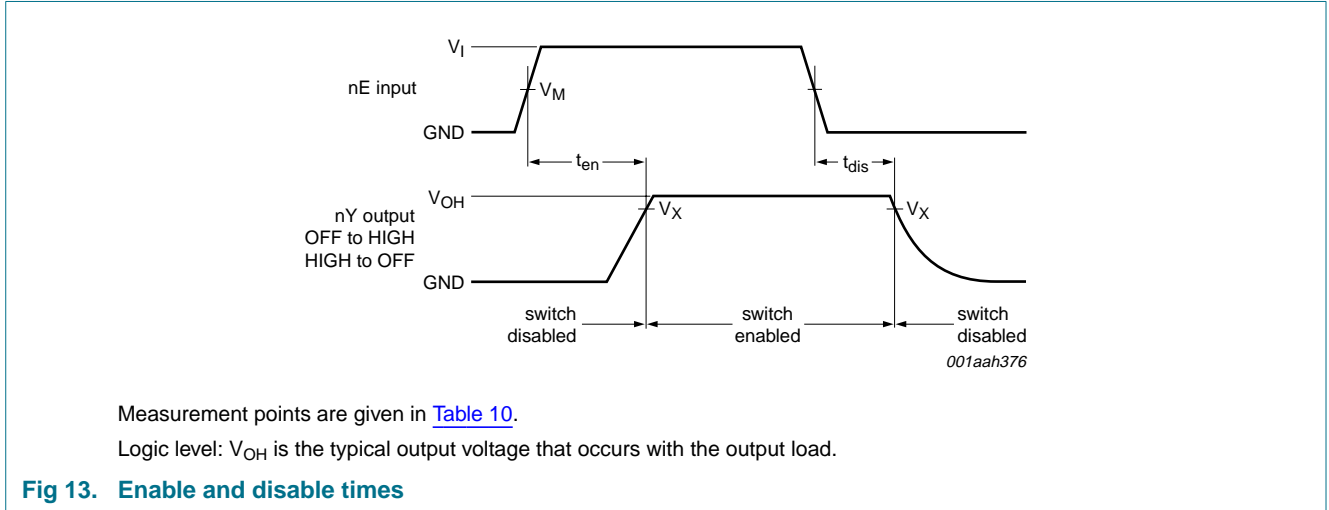
**Table 9. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see [Figure 14](#).

| Symbol           | Parameter    | Conditions                                 | 25 °C |                    |     | -40 °C to +125 °C |             |              | Unit |
|------------------|--------------|--|-------|--------------------|-----|-------------------|-------------|--------------|------|
|                  |              |  | Min   | Typ <sup>[1]</sup> | Max | Min               | Max (85 °C) | Max (125 °C) |      |
| t <sub>en</sub>  | enable time  | E to Z or Y; see <a href="#">Figure 13</a> |       |                    |     |                   |             |              |      |
|                  |              | V <sub>CC</sub> = 1.4 V to 1.6 V           | -     | 27                 | 41  | -                 | 44          | 48           | ns   |
|                  |              | V <sub>CC</sub> = 1.65 V to 1.95 V         | -     | 22                 | 27  | -                 | 34          | 36           | ns   |
|                  |              | V <sub>CC</sub> = 2.3 V to 2.7 V           | -     | 17                 | 20  | -                 | 27          | 30           | ns   |
| t <sub>dis</sub> | disable time | E to Z or Y; see <a href="#">Figure 13</a> |       |                    |     |                   |             |              |      |
|                  |              | V <sub>CC</sub> = 1.4 V to 1.6 V           | -     | 9                  | 18  | -                 | 19          | 21           | ns   |
|                  |              | V <sub>CC</sub> = 1.65 V to 1.95 V         | -     | 7                  | 13  | -                 | 15          | 16           | ns   |
|                  |              | V <sub>CC</sub> = 2.3 V to 2.7 V           | -     | 4                  | 8   | -                 | 9           | 10           | ns   |
|                  |              | V <sub>CC</sub> = 2.7 V to 3.6 V           | -     | 4                  | 8   | -                 | 8           | 9            | ns   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.5 V, 1.8 V, 2.5 V and 3.3 V respectively.

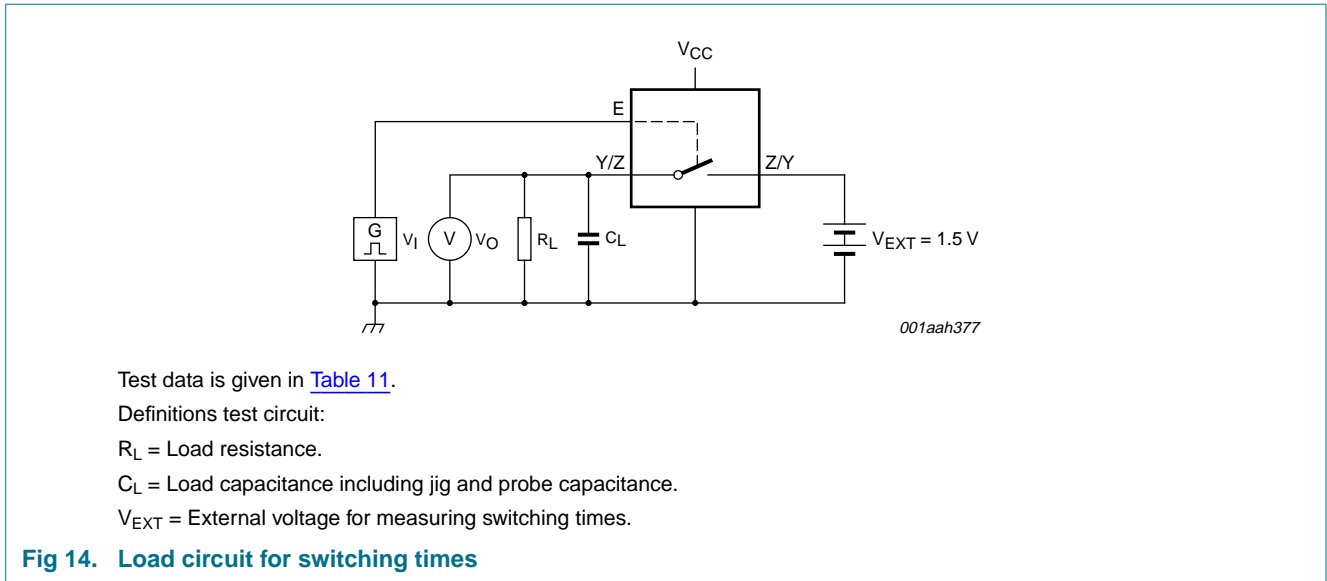
### 12.1 Waveform and test circuits



**Table 10. Measurement points**

| Supply voltage  | Input              | Output             |
|-----------------|--------------------|--------------------|
| V <sub>CC</sub> | V <sub>M</sub>     | V <sub>X</sub>     |
| 1.4 V to 3.6 V  | 0.5V <sub>CC</sub> | 0.9V <sub>OH</sub> |





**Table 11. Test data**

| Supply voltage | Input    |               | Load  |             |
|----------------|----------|---------------|-------|-------------|
| $V_{CC}$       | $V_I$    | $t_r, t_f$    | $C_L$ | $R_L$       |
| 1.4 V to 3.6 V | $V_{CC}$ | $\leq 2.5$ ns | 35 pF | 50 $\Omega$ |

## 12.2 Additional dynamic characteristics

**Table 12. Additional dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \leq 2.5$  ns.

| Symbol         | Parameter                 | Conditions   | 25 °C |       |     | Unit |
|----------------|---------------------------|--|-------|-------|-----|------|
|                |                           |  | Min   | Typ   | Max |      |
| THD            | total harmonic distortion | $f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$ ; see <a href="#">Figure 15</a> <sup>[1]</sup>  |       |       |     |      |
|                |                           | $V_{CC} = 1.4$ V; $V_I = 1$ V (p-p)  | -     | 0.15  | -   | %    |
|                |                           | $V_{CC} = 1.65$ V; $V_I = 1.2$ V (p-p)   | -     | 0.10  | -   | %    |
|                |                           | $V_{CC} = 2.3$ V; $V_I = 1.5$ V (p-p)  | -     | 0.015 | -   | %    |
|                |                           | $V_{CC} = 2.7$ V; $V_I = 2$ V (p-p)  | -     | 0.024 | -   | %    |
| $f_{(-3dB)}$   | -3 dB frequency response  | $R_L = 50 \Omega$ ; see <a href="#">Figure 16</a> <sup>[1]</sup><br>$V_{CC} = 1.4$ V to 3.6 V  | -     | 60    | -   | MHz  |
| $\alpha_{iso}$ | isolation (OFF-state)     | $f_i = 100$ kHz; $R_L = 50 \Omega$ ; see <a href="#">Figure 17</a> <sup>[1]</sup><br>$V_{CC} = 1.4$ V to 3.6 V                                     | -     | -90   | -   | dB   |
| $V_{ct}$       | crosstalk voltage         | between digital inputs and switch;<br>$f_i = 1$ MHz; $C_L = 50$ pF; $R_L = 50 \Omega$ ; see <a href="#">Figure 18</a><br>$V_{CC} = 1.4$ V to 3.6 V | -     | 0.16  | -   | V    |

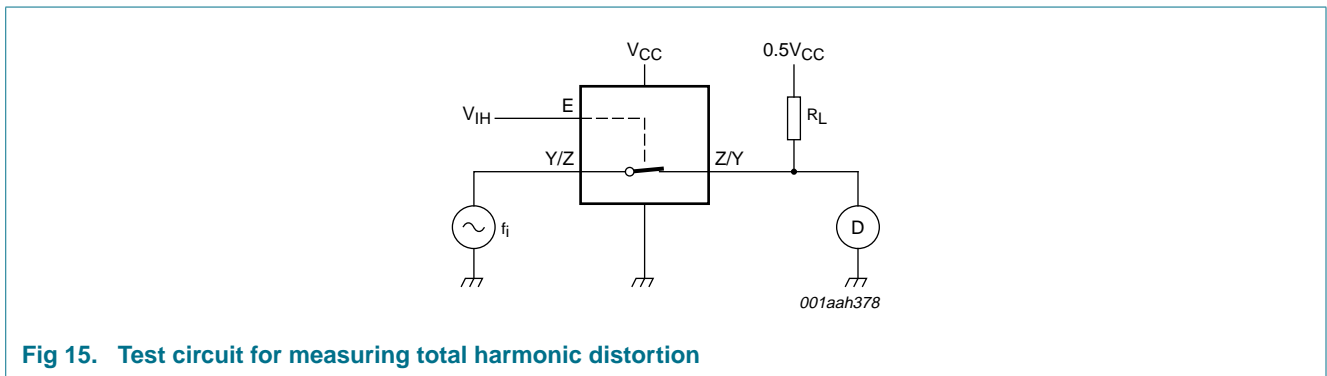
**Table 12. Additional dynamic characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = \text{GND}$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \leq 2.5 \text{ ns}$ .

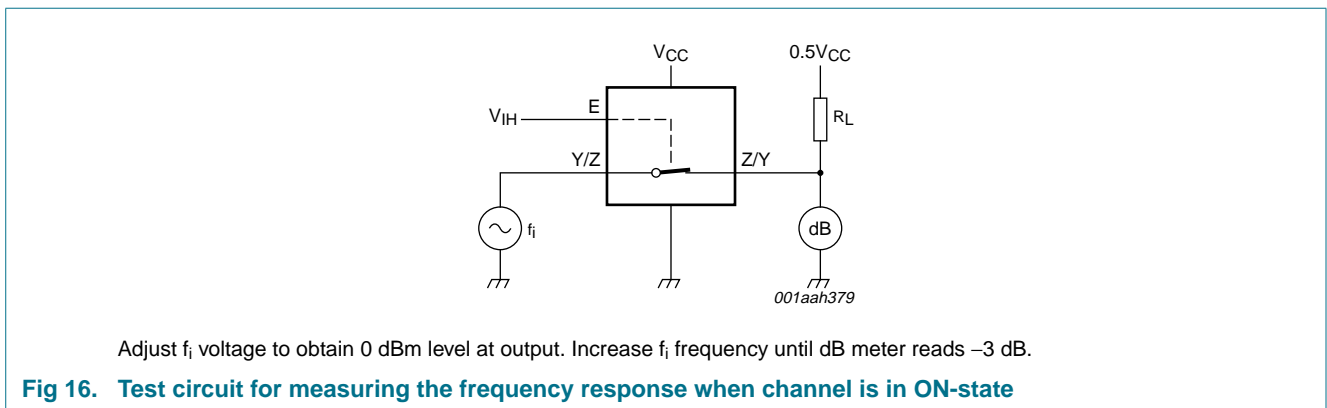
| Symbol    | Parameter        | Conditions   | 25 °C |     |     | Unit |
|-----------|------------------|--|-------|-----|-----|------|
|           |                  |  | Min   | Typ | Max |      |
| $Q_{inj}$ | charge injection | $f_i = 1 \text{ MHz}$ ; $C_L = 0.1 \text{ nF}$ ; $R_L = 1 \text{ M}\Omega$ ; $V_{gen} = 0 \text{ V}$ ;<br>$R_{gen} = 0 \Omega$ ; see <a href="#">Figure 19</a> | -     | 3   | -   | pC   |
|           |                  |  | -     | 3   | -   | pC   |
|           |                  |  | -     | 3   | -   | pC   |
|           |                  |  | -     | 3   | -   | pC   |

[1]  $f_i$  is biased at  $0.5V_{CC}$ .

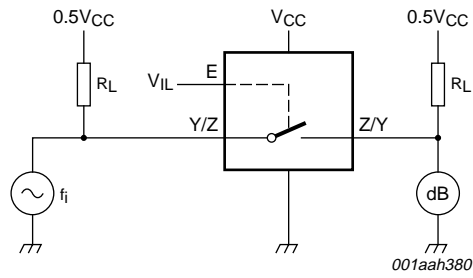
### 12.3 Test circuits



**Fig 15. Test circuit for measuring total harmonic distortion**

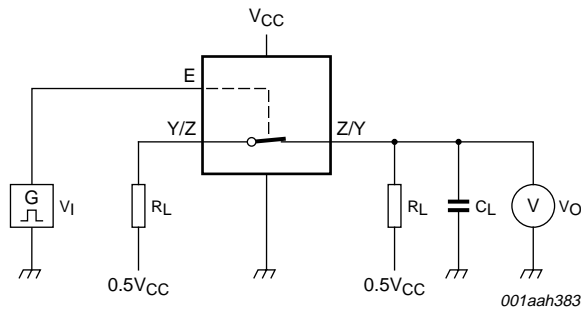


**Fig 16. Test circuit for measuring the frequency response when channel is in ON-state**

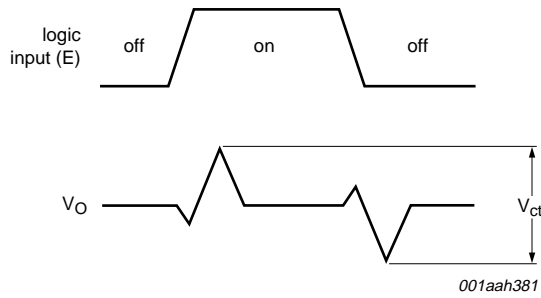


Adjust  $f_i$  voltage to obtain 0 dBm level at input.

**Fig 17. Test circuit for measuring isolation (OFF-state)**

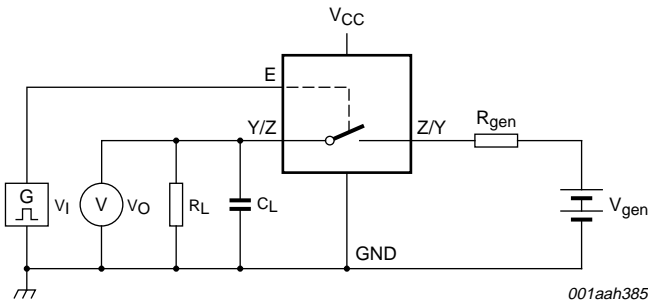


a. Test circuit

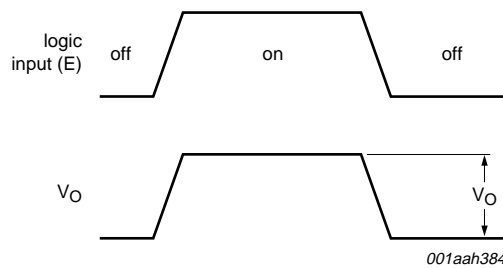


b. Input and output pulse definitions

**Fig 18. Test circuit for measuring crosstalk voltage between digital inputs and switch**



a. Test circuit



b. Input and output pulse definitions

Definition:  $Q_{inj} = \Delta V_O \times C_L$ .

$\Delta V_O$  = output voltage variation.

$R_{gen}$  = generator resistance.

$V_{gen}$  = generator voltage.

**Fig 19. Test circuit for measuring charge injection**

13. Package outline

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

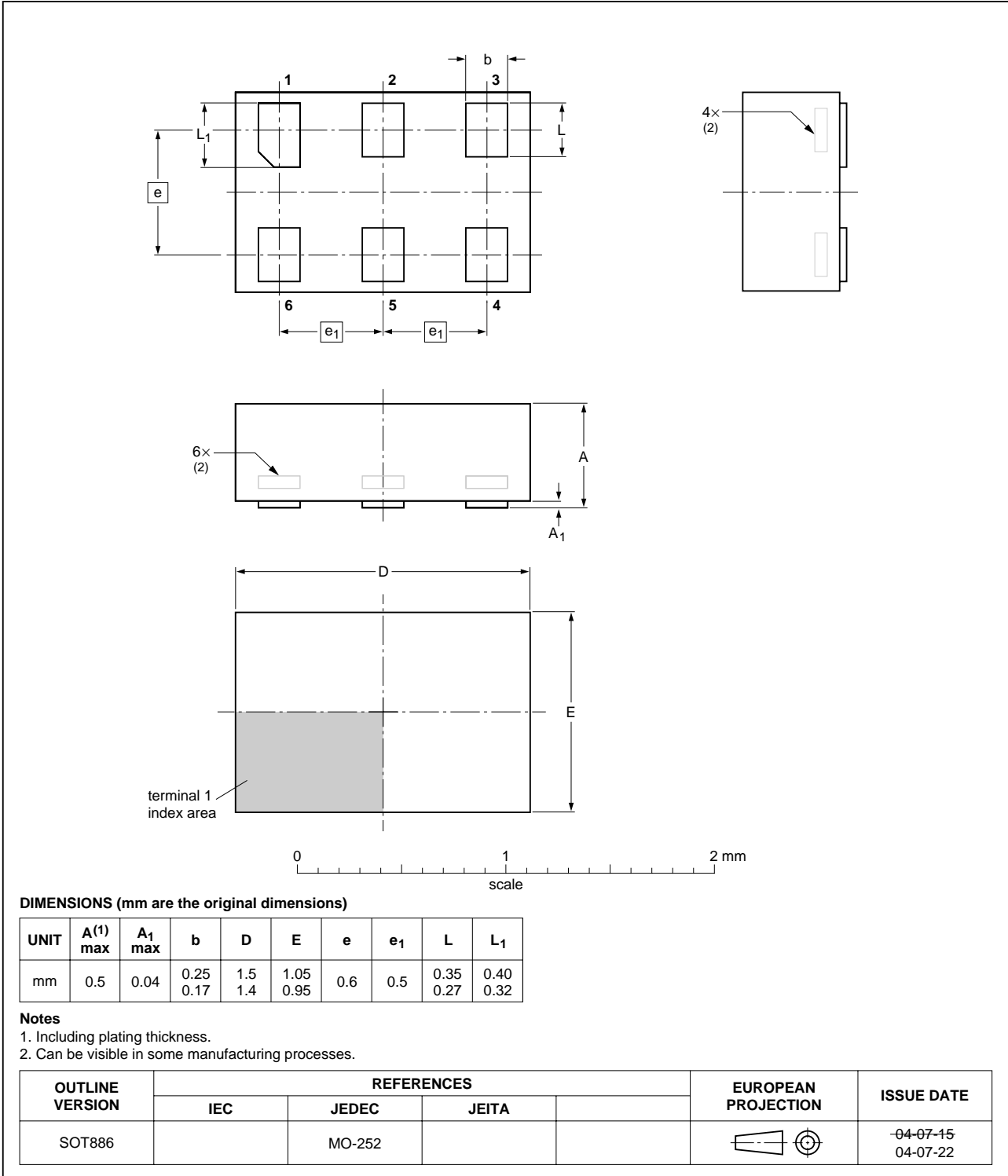


Fig 20. Package outline SOT886 (XSON6)

## 14. Abbreviations

Table 13. Abbreviations

| Acronym | Description                             |
|---------|---|
| CDM     | Charged-Device Model                    |
| CMOS    | Complementary Metal Oxide Semiconductor |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 15. Revision history

Table 14. Revision history

| Document ID    | Release date  | Data sheet status  | Change notice | Supersedes |
|----------------|---|--------------------|---------------|------------|
| NX3L1G66_2     | 20080307  | Product data sheet | -             | NX3L1G66_1 |
| Modifications: | <ul style="list-style-type: none"><li>• <a href="#">Section 2 "Features"</a>:<br/>Changed: Latch-up performance changed from level B to level A</li></ul> |                    |               |            |
| NX3L1G66_1     | 20080103  | Product data sheet | -             | -          |

## 16. Legal information

### 16.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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